

Patent Assignment Abstract of Title

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Title: Liquid crystal device, method of manufacturing liquid crystal device and electronic apparatus

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L Number	Hits	Search Text	DB	Time stamp
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2	88	hagiwara-takeshi.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:25
3	109	hinata-shoji.in. hagiwara-takeshi.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:25
4	30085	349\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:25
5	19	(hinata-shoji.in. hagiwara-takeshi.in.) and 349\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:32
6	1119	(349/113-114).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:32
7	395614	ito (indium adj tin adj oxide) indium-tin-oxide (metal adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:34
8	939797	reflect\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:34
9	7897	(ito (indium adj tin adj oxide) indium-tin-oxide (metal adj oxide)) same reflect\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:34
10	280	((349/113-114).ccls.) and ((ito (indium adj tin adj oxide) indium-tin-oxide (metal adj oxide)) same reflect\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:34
11	1583136	substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:35
12	26744	(ito (indium adj tin adj oxide) indium-tin-oxide (metal adj oxide)) near10 substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:35
13	1618	reflect\$3 same ((ito (indium adj tin adj oxide) indium-tin-oxide (metal adj oxide)) near10 substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:35
14	116	((349/113-114).ccls.) and (reflect\$3 same ((ito (indium adj tin adj oxide) indium-tin-oxide (metal adj oxide)) near10 substrate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/11 17:36